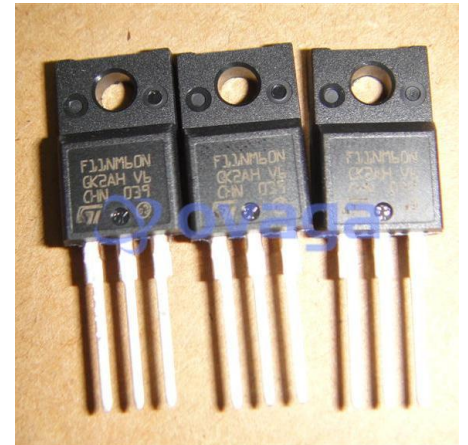


N-channel 600V - 0.37 \sim - 10A - TO-220/FP- I²PAK - DPAK second generation MDmesh¹⁰ Power MOSFET, MOSFET N-channel MOSFET

Manufacturers	STMicroelectronics, Inc
Package/Case	TO-220FP
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for STF11NM60N or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

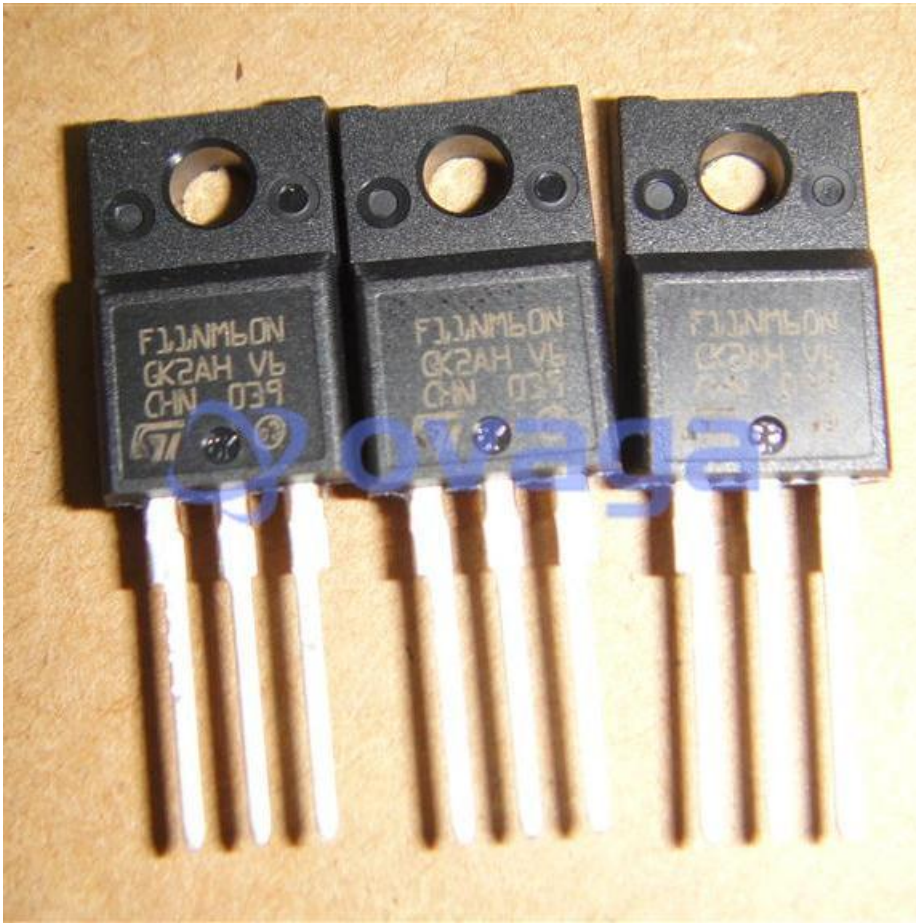
STF11NM60N is a power MOSFET transistor manufactured by STMicroelectronics.

Features

- It has a drain-source voltage rating of 600V
- It has a maximum continuous drain current of 11A
- It has a low on-resistance of 0.35 ohms
- It has a fast switching speed and low gate charge
- It is designed to operate at high temperatures, making it suitable for use in industrial applications.

Application

- It can be used in various power electronics applications, including switch-mode power supplies, lighting, motor control, and inverters.
- It is commonly used in power conversion circuits for energy-efficient designs.



Related Products



[STF42N65M5](#)

STMicroelectronics, Inc
TO-220FP



[STN3NF06](#)

STMicroelectronics, Inc
SOT-223



[STP11NM60FD](#)

STMicroelectronics, Inc
TO-220



[STP11NK50Z](#)

STMicroelectronics, Inc
TO-220-3



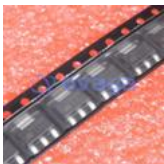
[STB75NF75](#)

STMicroelectronics, Inc
TO-263



[STN951](#)

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SOT-223



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